NSN 5961-01-175-2586

A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-175-2586 **Inclosure Material:** Glass **Overall Length:** 0.380 inches **Terminal Length:** 1.062 inches **Overall Diameter:** 0.210 inches **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 36.0 nonrepetitive peak reverse voltage and 30.0 reverse voltage, dc and 30.0 working peak reverse voltage and 21.0 reverse voltage, total rms **Current Rating Per Characteristic:** 5.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: